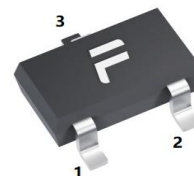
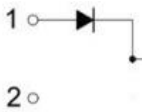
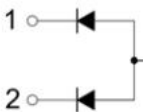
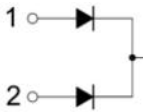
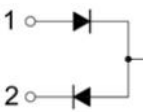


SOT-23 Schottky Barrier Diode 肖特基势垒二极管



Internal Configuration & Device Marking 内部结构与产品打标

Type 型号	BAT721	BAT721A	BAT721C	BAT721S
Pin 管脚				
Mark 打标	L7	L8	L9	L0

Absolute Maximum Ratings 最大额定值

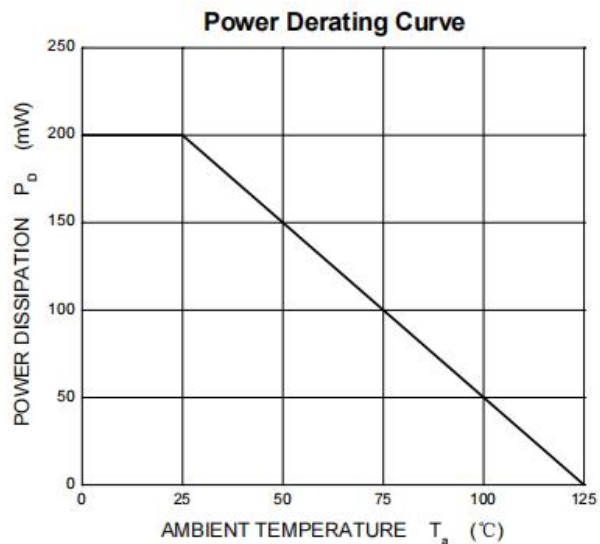
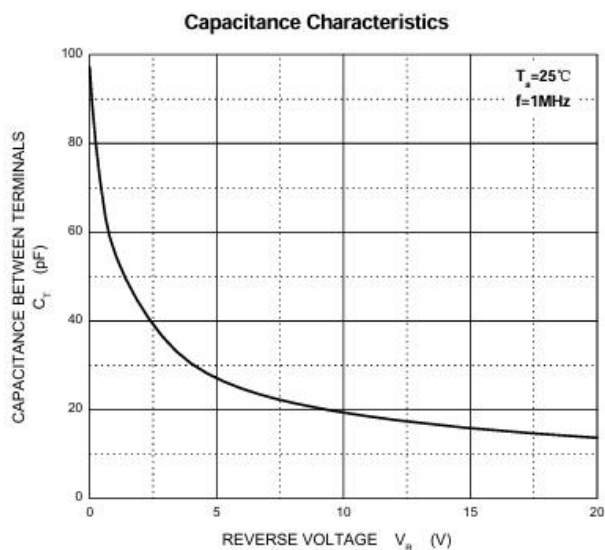
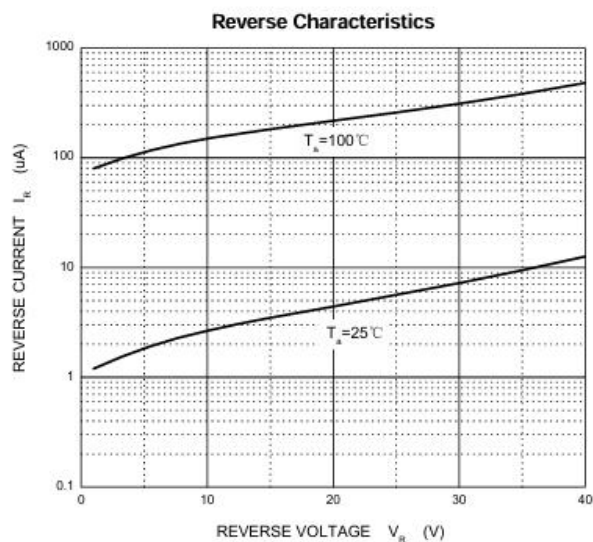
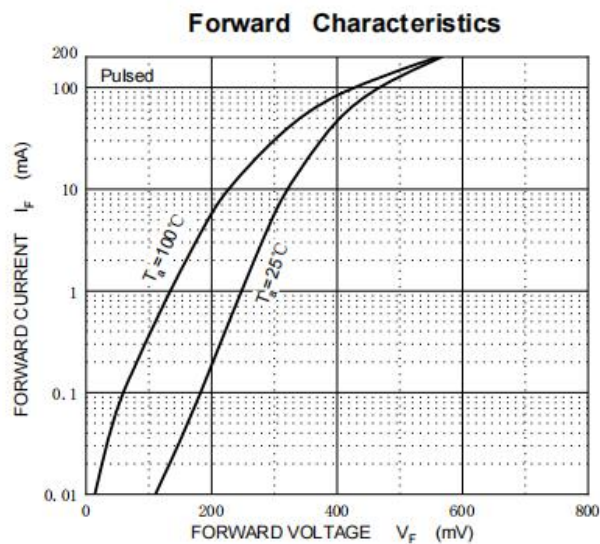
Characteristic 特性参数	Symbol 符号	Rat 额定值	Unit 单位
DC Reverse Voltage 直流反向电压	V_R	40	V
RMS Reverse Voltage 直流反向电压均方根值	V_{RMS}	28	V
Forward Work Current 正向工作电流	$I_F(I_O)$	200	mA
Peak Forward Surge Current 正向峰值浪涌电流 (8.3ms single half sine-wave)	I_{FSM}	1000	mA
Power dissipation 耗散功率	$P_D(T_a=25^\circ C)$	200	mW
Thermal Resistance J-A 结到环境热阻	$R_{\theta JA}$	500	$^\circ C/W$
Junction and Storage Temperature 结温和储藏温度	T_J, T_{stg}	-55to+125 $^\circ C$	

Electrical Characteristics 电特性

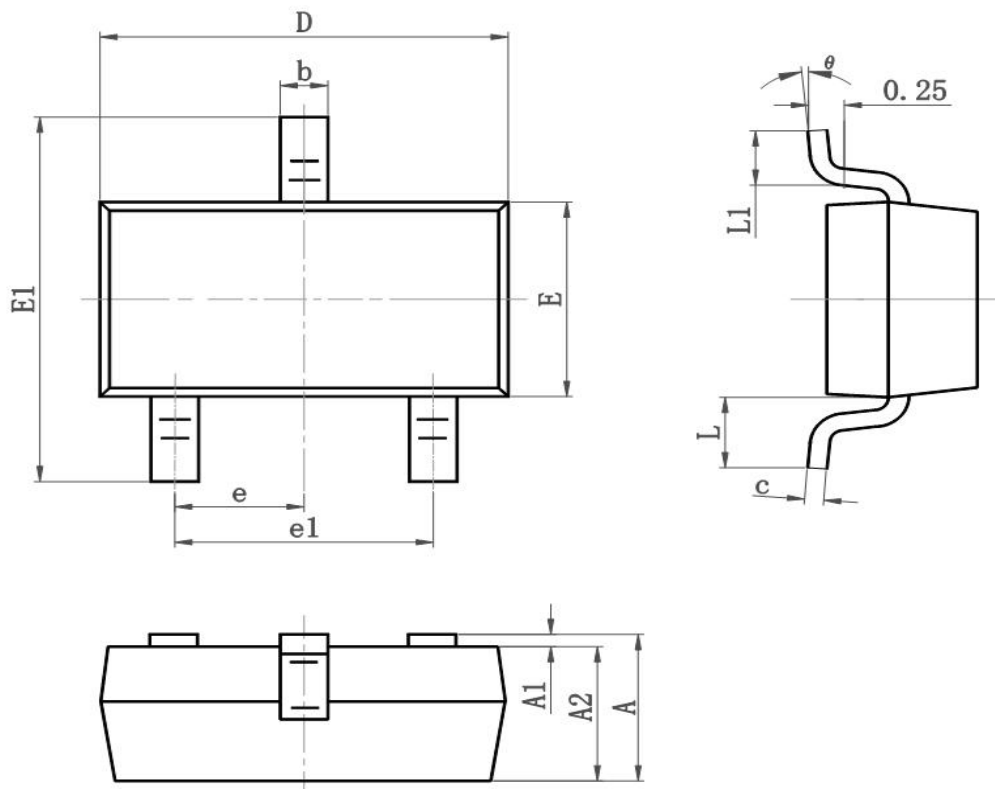
($T_A=25^\circ C$ unless otherwise noted 如无特殊说明, 温度为 $25^\circ C$)

Characteristic 特性参数	Symbol 符号	Min 最小值	Max 最大值	Unit 单位
Reverse Breakdown Voltage 反向击穿电压($I_R=100\mu A$)	$V_{(BR)}$	40	—	V
Reverse Leakage Current 反向漏电流($V_R=30V$)	I_R	—	5	μA
Forward Voltage($I_F=10mA$) 正向电压($I_F=20mA$) ($I_F=100mA$) ($I_F=200mA$)	V_F	—	0.3 0.37 0.45 0.6	V
Diode Capacitance 二极管电容($V_R=4V, f=1MHz$)	C_D	—	30	pF

■ Typical Characteristic Curve 典型特性曲线



■Dimension 外形封装尺寸



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.050	0.055
E1	2.250	2.550	0.089	0.100
e	0.900	1.00	0.035	0.039
e1	1.800	2.000	0.071	0.079
L	0.500	0.600	0.020	0.024
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°